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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/604,692	08/11/2003	HSIANG-LAN LUNG	10156-US-PA	1691
JIANQ CHYUN INTELLECTUAL PROPERTY OFFICE 7 FLOOR-1, NO. 100			EXAMINER	
			WARREN, MATTHEW E	
ROOSEVELT ROAD, SECTION 2 TAIPEI, 100		ART UNIT	PAPER NUMBER	
TAIWAN			2815	
. •				
	•		NOTIFICATION DATE	DELIVERY MODE
			01/14/2008	ELECTRONIC

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

USA@JCIPGROUP.COM.TW

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	10/604,692	LUNG ET AL.				
Office Action Summary	Examiner	Art Unit				
	Matthew E. Warren	2815				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period was realized to reply within the set or extended period for reply will, by statute. Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be timulated and will expire SIX (6) MONTHS from cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).				
Status ⁻						
·	Responsive to communication(s) filed on <u>01 October 2007</u> .					
,	·					
•	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims						
4)	wn from consideration.					
Application Papers						
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	epted or b) objected to by the drawing(s) be held in abeyance. Section is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some * c) None of:  1. Certified copies of the priority documents have been received.  2. Certified copies of the priority documents have been received in Application No.  3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.						
Attachment(s)						
1) Notice of References Cited (PTO-892)  4) Interview Summary (PTO-413)  Paper No(s)/Mail Date.						
Notice of Draftsperson's Patent Drawing Review (PTO-948)     Information Disclosure Statement(s) (PTO/SB/08)     Paper No(s)/Mail Date	5) Notice of Informal F 6) Other:					

### DETAILED ACTION

This Office Action is in response to the Amendment filed on October 1, 2007.

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language. .

Claims 1, 4-6, 8-10, 12, and 35-37 are rejected under 35 U.S.C. 102(e) as being anticipated by Haspeslagh (US 6,580,120 B2).

In re claims 1 and 35, Haspeslagh shows (figs. 2h, 3, 5) split gate non-volatile memory comprising: a substrate: a charge-trapping layer (16 = 4, 5, 6) on the substrate; a split gate (7, 11) as a whole located over the charge-trapping layer and a source/drain (14a, 13a) in the substrate beside the split gate; wherein the split gate includes at least two neighboring conductive pieces (7, 11) that are shorted with each other (W1, W2, W3, connect 7, 11, and 7 together in fig. 5) and have two opposite edge portions together causing, in operation of the memory cell a locally stronger electric field such that only one coding region (bri.i:1) is defined (only one bit in layer 16), by the two neighboring conductive pieces, in the charge trapping layer around the two opposite edge portions.

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In re claim 4, Haspeslagh shows (figs. 2h, 3, 5) the conductive pieces of the split gate include a pair of conductive spacers (7) and a conductive layer (11) between the pair of conductive spacers.

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In re claim 5, Haspeslagh shows (figs. 2h, 3, 5) the pair of conductive spacers (7) are arranged with two substantially vertical sidewalls thereof adjacent to the source/drain (14a and 13a)

In re claim 6, Haspeslagh shows (figs. 2h, 3, 5) an insulator (12) on the source/drain, wherein the pair of conductive spacers (7) are disposed on the sidewalls of the insulator.

In re claim 8, Haspeslagh shows (figs. 2h, 3, 5) the conductive pieces (7,11) are separated from each other by a dielectric layer (17).

In re claim 9, Haspeslagh discloses (col. 6, lines 39-47) that the split gate comprises polysilicon.

In re claim 10, Haspeslagh discloses (col. 6, line 59 – col. 7, line 27), the charge-trapping layer (16) comprises a silicon nitride layer (5) disposed between two silicon oxide layers (4, 6).

With regards to remaining limitations of claim 35, and claims 36-37, the claimed "programming operation" is not considered to add any structure to the claimed device and is considered to be intended use of the device. It has been held that a recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus satisfying the claimed structural limitations. Ex parte Masham, 2 USPQ2d 1647 (1987).

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In re claim 12, Haspeslagh discloses (col. 6, lines 4-26) that the substrate comprises a p-substrate, and the source/drain comprises an n-type source/drain.

Claim 11 is rejected under 35 USC § 103 (a) as being unpatentable over Haspeslagh (US 6,580,120 B2) applied to claim 1 above, and further in view of Schwabe et al. (US 4,257,832).

In re claim 11, Haspeslagh does not show the charge-trapping layer comprising aluminum oxide ( $Al_2O_3$ ). Schwabe discloses in col. 3, lines 11-15 a charge- trapping layer comprises aluminum oxide ( $Al_2O_3$ ). It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the trapping layer of Haspeslagh by using  $Al_2O_3$  as a tunnel oxide taught by Schwabe to form a suitable charge trapping layer.

## Response to Arguments

Applicant's arguments with respect to claims 1, 4-6, 8-12 and 35-37 have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

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A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew E. Warren whose telephone number is (571) 272-1737. The examiner can normally be reached on Mon-Thur and alternating Fri 9:00-5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kenneth Parker can be reached on (571) 272-2298. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Matthew E. Warren

January 3, 2008

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